

SUPPORTING INFORMATION

Rational Design of 2D Ferroelectric Heterogeneous Catalysts for Controllable Hydrogen Evolution Reaction

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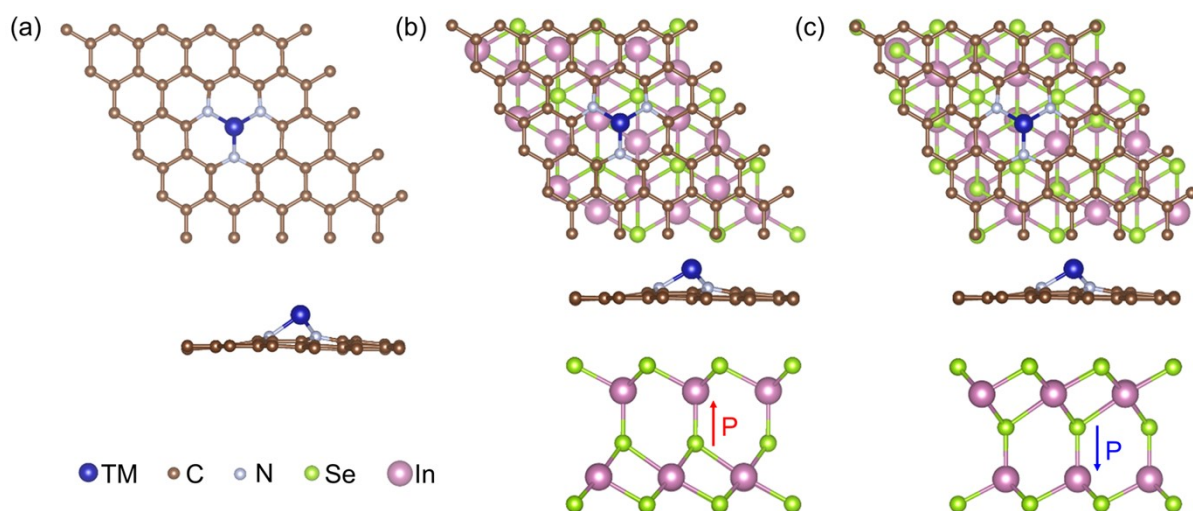


Fig. S1 Top and side views of the optimized structures for (a) TMN₃, (b) TMN₃/P[↑]-In₂Se₃, and (c) TMN₃/P[↓]-In₂Se₃.

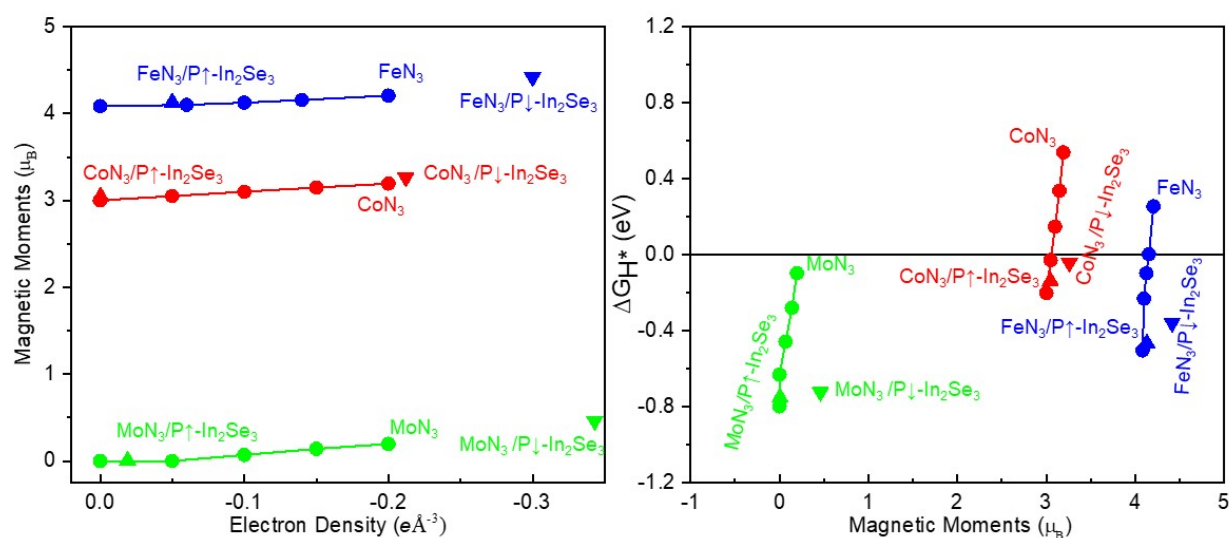


Fig. S2 Relationships between the (a) magnetic moment and electron density and (b) Gibbs free energy of ΔG_{H^*} and magnetic moment of TMN₃ and TMN₃/In₂Se₃ catalysts.

Fig. S2a shows the inverse relationship between the magnetic moment of TMN₃-H* and the different electron densities. It is found that the electron density can influence the magnetic moment of TMN₃-H*. On the other hand, the notable deviations from the linear trend between magnetic moment and electron density of TMN₃/P[↑]-In₂Se₃ and TMN₃/P[↓]-In₂Se₃ can be also observed. It can be attributed to the electrostatic potential difference after introducing the FE substrate and the intrinsic polarization of In₂Se₃, which is partially responsible for the variation of the magnetic moment. As shown in Fig. S2b, the larger magnetic moment adjusts the catalytic activity of TM sites, resulting in weaker adsorption of the H atom on the TMN₃

catalyst, ascribed to the adjustment of empty and occupied d-orbitals of TM atoms. Further analysis can be seen in Fig. 1c-e, 2b, and S4.

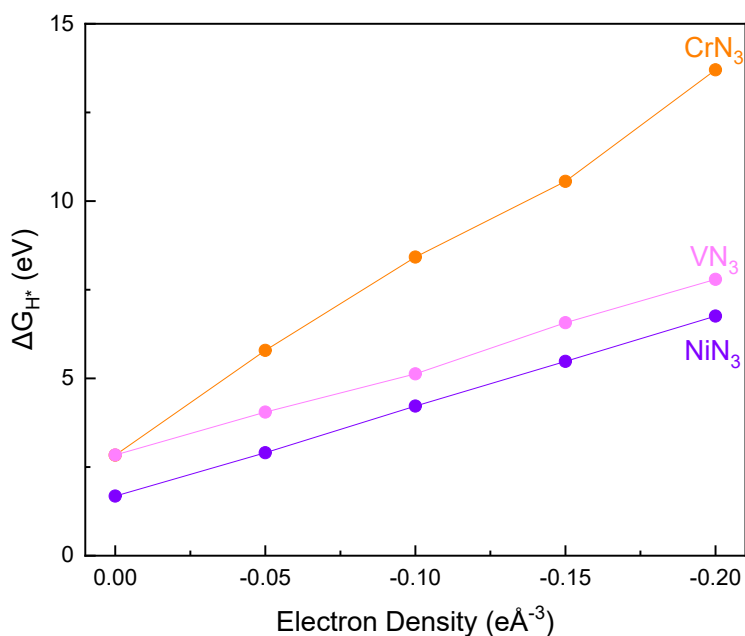


Fig. S3 Relationships between the Gibbs free energy of ΔG_{H^*} and electron density of other TMN₃ catalysts.

One can see clearly from Fig. S3 that a linear relationship between the electron density and ΔG_{H^*} for other studied TMN₃ catalysts (TM = Cr, Ni, and V), indicates electron density is an effective factor to modulate the HER performance. However, these three TMN₃ catalysts show weak HER activity, thus, we neglect these TMN₃ catalysts in the following discussion.

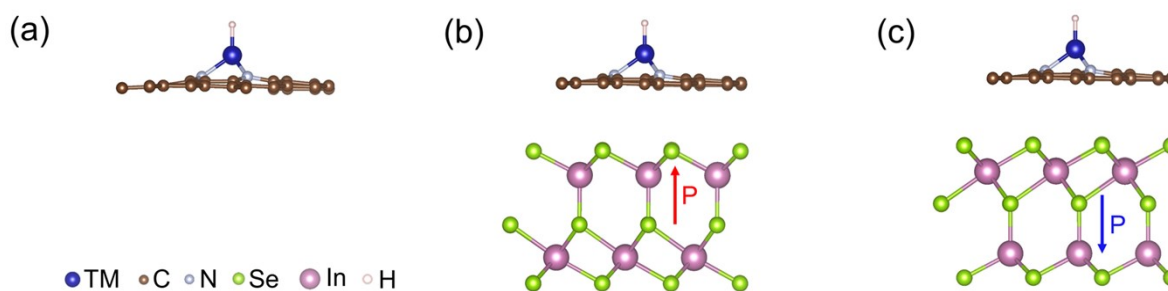


Fig. S4 Side views of the optimized structures for (a) TMN₃-H*, (b) TMN₃/P[↑]-In₂Se₃-H*, and (c) TMN₃/P[↓]-In₂Se₃-H*.

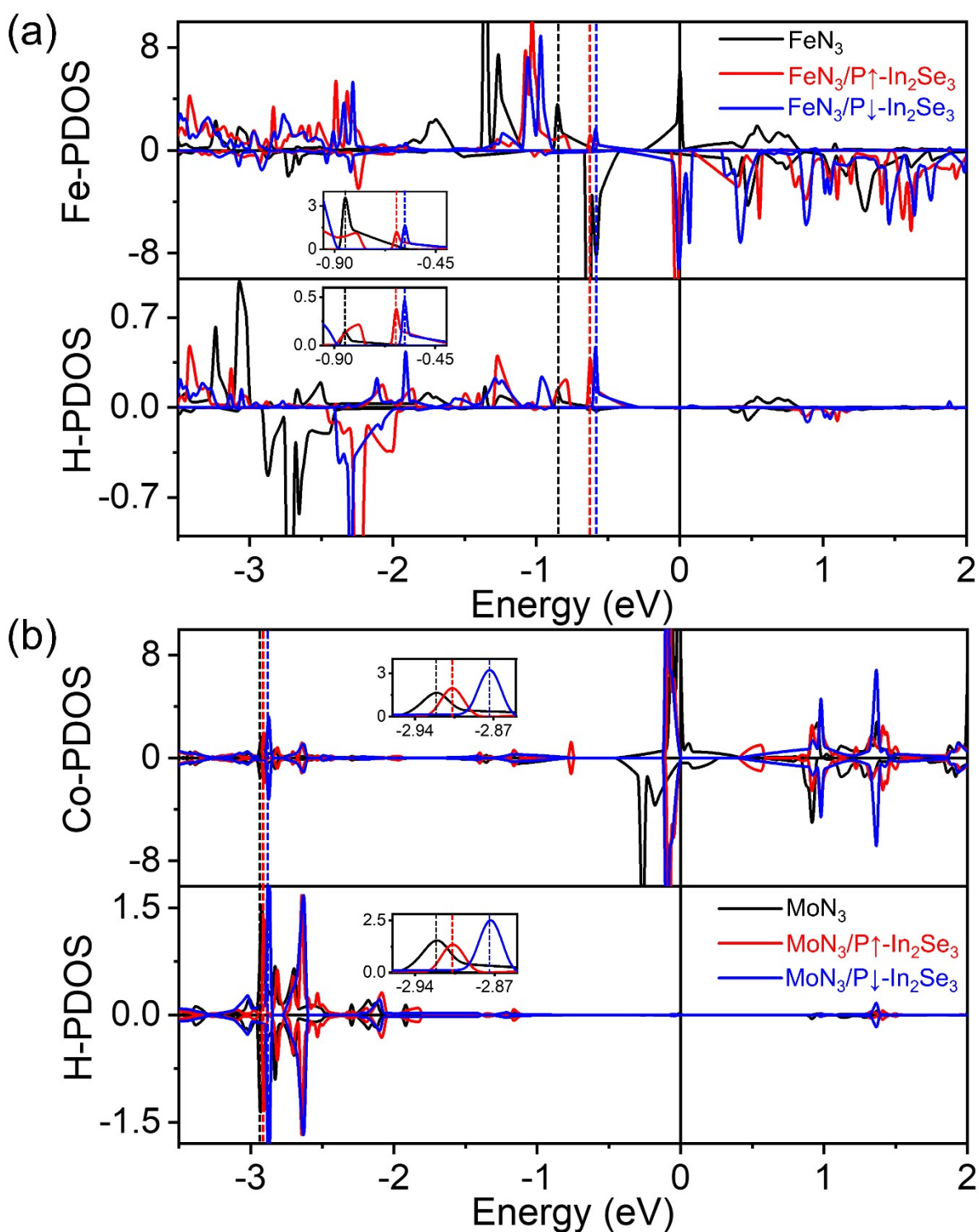


Fig. S5 PDOSs of TM-d and H-s orbitals for TMN₃ and TMN₃/In₂Se₃ with different polarization directions: (a) FeN₃ and (b) MoN₃.

From Fig. S5, we can see the PDOS for Fe/Mo-d and H-s orbitals of pure TMN₃ and TMN₃/In₂Se₃ are plotted in Fig. S4. One we can see the obvious shift of Fe/Mo–H bonding state when Fe/MoN₃ is placed on the In₂Se₃ with two different polarization directions, and it agrees with the changes of ΔG_{H^*} values.

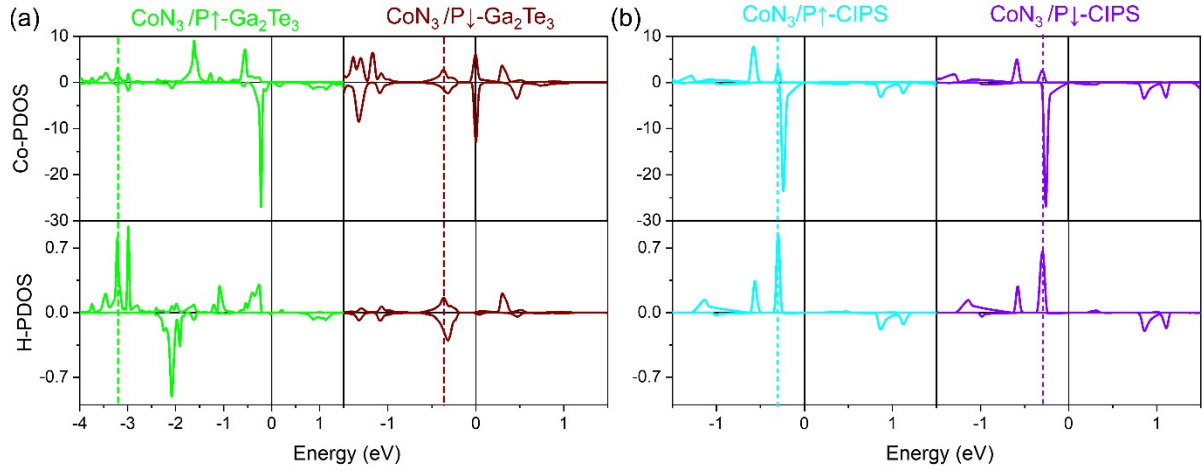


Fig. S6 PDOSs plot for (a) $\text{CoN}_3/\text{Ga}_2\text{Te}_3$ and (b) CoN_3/CIPS with different polarization directions.

Fig. S6 shows the PDOS for Co-d and H-s orbitals of $\text{CoN}_3/\text{Ga}_2\text{Te}_3$ and CoN_3/CIPS with two different polarization directions. In Fig S6a, when Co/MoN₃ is placed on the P[↑]-Ga₂Te₃, the overlap between the Co-d and H-s orbitals is located at the deep level, demonstrating the relatively high bonding interaction between the Co and H atoms. In contrast, the hybridization between the Co-d and H-s orbitals moves towards the Fermi level when the polarization direction of Ga₂Te₃ points down, indicating the weak chemical binding of Co-H bond.

As provided in Fig. S6b, one can see clearly that the PDOS of Co-d and H-s orbitals remains essentially unchanged in both polarization directions of CIPS, leading to the feeble changes of the magnetic moment and electron transfer. The phenomenon can be attributed to CIPS is a layered ferroelectric which has a relatively weak van der Waals interaction between the catalyst/substrate interface, leading to a weak response to the polarization switching.

Table S1. The H adsorptions on the pure TMN₃ and TMN₃/In₂Se₃: Gibbs free energy change of H* intermediate (ΔG_{H^*} in eV), total magnetic moment of TMN₃ (M in μ_{B}), electron transfer of TM atoms (Q_{TM} in e/atom), N atoms (Q_{N} in e/unit cell), In₂Se₃ substrate ($Q_{\text{In}_2\text{Se}_3}$ in e/unit cell), and H atoms (Q_{H} in e/atom).

System	ΔG_{H^*}	M	Q_{TM}	Q_{N}	$Q_{\text{In}_2\text{Se}_3}$	Q_{H}
FeN ₃	-0.504	4.08	-1.09	3.68	N/A	0.45
FeN ₃ /P [↑] -In ₂ Se ₃	-0.465	4.13	-1.09	3.69	0.05	0.44
FeN ₃ /P [↓] -In ₂ Se ₃	-0.360	4.42	-1.13	3.719	0.30	0.41
MoN ₃	-0.798	0.00	-1.43	3.459	N/A	0.45
MoN ₃ /P [↑] -In ₂ Se ₃	-0.751	0.00	-1.43	3.46	0.02	0.43
MoN ₃ /P [↓] -In ₂ Se ₃	-0.723	0.46	-1.42	3.48	0.34	0.43

Table S2. Gibbs free energy change of H* intermediate (ΔG_{H^*} in eV) for pure TMN₃.

System	ΔG_{H^*}
CrN ₃	2.836
NiN ₃	1.680
VN ₃	2.840

Table S3. The magnetic moment of the catalytic TM sites and the surrounding atoms under the different electron doping.

Electro n Doping	CoN ₃					FeN ₃					MoN ₃				
	Co	N	C	H	Total I	Fe	N	C	H	Total I	Mo	N	C	H	Total I
0	2.30	0.09	0.01	0.02	3.00	3.44	0.08	0.01	0.00	4.08	0.00	0.00	0.00	0.00	0.00
-0.05	2.31	0.10	0.01	0.02	3.05	3.49	0.08	0.01	0.00	4.10	0.00	0.00	0.00	0.00	0.00
-0.1	2.33	0.10	0.01	0.02	3.10	3.49	0.08	0.01	0.00	4.13	0.11	0.00	0.00	0.00	0.07
-0.15	2.34	0.10	0.01	0.02	3.15	3.50	0.09	0.01	0.00	4.16	0.22	0.01	0.00	0.00	0.14
-0.2	2.36	0.10	0.01	0.02	3.19	3.51	0.09	0.00	0.00	4.21	0.31	0.01	0.00	0.00	0.20

Table S4. The magnetic moment of the catalytic TM sites and the surrounding atoms before and after absorbed H atom. The values in brackets denote the magnetic moment after absorbed H atom.

System		TMN ₃	TMN ₃ /P \uparrow -In ₂ Se ₃	TMN ₃ /P \downarrow -In ₂ Se ₃
Co	Co	1.90 (2.30)	1.94 (2.30)	2.00 (2.30)
	N	0.07 (0.09)	0.07 (0.09)	0.09 (0.10)
	C	0.01 (0.01)	0.00 (0.01)	0.00 (0.00)
	H	N/A (0.02)	N/A (0.02)	N/A (0.02)
	Total	2.29 (3.00)	2.33 (3.01)	2.49 (3.26)
	Fe	Fe	3.01 (3.44)	3.04 (3.48)
Fe	N	0.05 (0.08)	0.06 (0.09)	0.07 (0.09)
	C	0.01 (0.01)	0.00 (0.01)	0.00 (0.00)
	H	N/A (0.00)	N/A (0.00)	N/A (0.00)
	Total	3.19 (4.08)	3.27 (4.13)	3.50 (4.42)
	Mo	Mo	1.18 (0.00)	1.32 (0.00)
Mo	N	0.02 (0.00)	0.02 (0.00)	0.02 (0.01)
	C	0.01 (0.00)	0.00 (0.00)	0.00 (0.00)
	H	N/A (0.00)	N/A (0.00)	N/A (0.00)
	Total	1.02	1.13	1.53

(0.00)

(0.00)

(0.46)